

### 1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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Thank you for your cooperation and understanding,

WeEn Semiconductors



### DISCRETE SEMICONDUCTORS

## DATA SHEET

# BYV42E, BYV42EB series Rectifier diodes ultrafast, rugged

**Product specification** 

July 1998



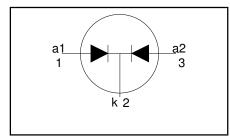
### **Rectifier diodes** ultrafast, rugged

### BYV42E, BYV42EB series

### **FEATURES**

- Low forward volt drop
- · Fast switching
- Soft recovery characteristicReverse surge capability
- High thermal cycling performanceLow thermal resistance

### **SYMBOL**



### **QUICK REFERENCE DATA**

$$V_{R} = 150 \text{ V}/ 200 \text{ V}$$

$$V_{F} \leq 0.85 \text{ V}$$

$$I_{O(AV)} = 30 \text{ A}$$

$$I_{RRM} = 0.2 \text{ A}$$

$$t_{rr} \leq 28 \text{ ns}$$

### **GENERAL DESCRIPTION**

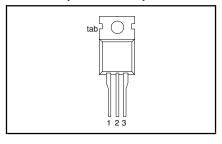
Dual, ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV42E series is supplied in the SOT78 conventional leaded package. The BYV42EB series is supplied in the SOT404 surface mounting package.

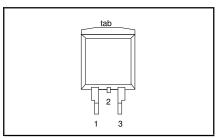
### **PINNING**

PIN	DESCRIPTION		
1	anode 1 (a)		
2	cathode (k) 1		
3 anode 2 (a)			
tab	cathode (k)		

### **SOT78 (TO220AB)**



### **SOT404**



### **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	M.A	UNIT	
		BYV42E / BYV42EB		-150	-200	
V <sub>RRM</sub>	Peak repetitive reverse voltage		-	150	200	l V
$oldsymbol{V}_RWM$	Crest working reverse voltage Continuous reverse voltage	T <sub>mb</sub> ≤ 144°C	-	150 150	200 200	] V
I <sub>O(AV)</sub>	Average rectified output current (both diodes conducting)	square wave $\delta = 0.5$ ; $T_{mb} \le 108$ °C	-	3	0	Α
I <sub>FRM</sub>	Repetitive peak forward current per diode	$t = 25 \mu s; \delta = 0.5;$ $T_{mb} \le 108 ^{\circ}C$	-	3	0	Α
I <sub>FSM</sub>	Non-repetitive peak forward	t = 10 ms	-	15	50	Α
	current per diode	t = 8.3 ms sinusoidal; with reapplied	-	16	60	A
I <sub>RRM</sub>	Repetitive peak reverse current per diode	$t_p = 2 \mu s; \delta = 0.001$	-	0	.2	A
I <sub>RSM</sub>	Non-repetitive peak reverse current per diode	t <sub>p</sub> = 100 μs	-	0	.2	Α
T <sub>stg</sub>	Storage temperature		-40	15	50	°C
T <sub>i</sub>	Operating junction temperature		-	1 1	50	°C

1. It is not possible to make connection to pin 2 of the SOT404 package

2. SOT78 package, For output currents in excess of 20 A, the cathode connection should be made to the mounting tab.

NXP Semiconductors Product specification

Rectifier diodes ultrafast, rugged

BYV42E, BYV42EB series

### **ESD LIMITING VALUE**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>C</sub>	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 kΩ	1	8	kV

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-mb}$ $R_{th j-a}$	Thermal resistance junction to mounting base Thermal resistance junction to ambient	per diode both diodes SOT78 package, in free air SOT404 and SOT428 packages, pcb mounted, minimum footprint, FR4 board	1 1 1	- 60 50	2.4 1.4 - -	K/W K/W K/W K/W

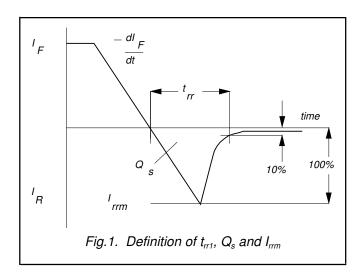
### **ELECTRICAL CHARACTERISTICS**

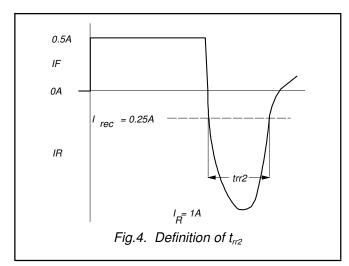
characteristics are per diode at T<sub>i</sub> = 25 °C unless otherwise stated

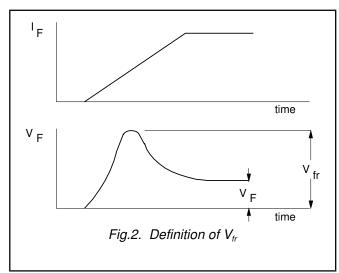
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{F}$	Forward voltage	$I_F = 15 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.78	0.85	V
· .		$ I_{\rm F}  = 15  {\rm A}$	-	0.95	1.05	V
		$I_{\rm F} = 30 \text{ A}$	-	1.00	1.20	V
l <sub>B</sub>	Reverse current	$V_R = V_{RWM}$ ; $T_i = 100  ^{\circ}C$	-	0.5	1	mΑ
		$V_{\rm R} = V_{\rm RWM}$	-	10	100	μΑ
$Q_s$	Reverse recovery charge	$II_{E} = 2 \text{ A}$ : $V_{D} \ge 30 \text{ V}$ : $-dI_{E}/dt = 20 \text{ A/us I}$	-	6	15	'nС
t <sub>rr1</sub>	Reverse recovery time	$ I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$	-	20	28	ns
	_	-dl <sub>=</sub> /dt = 100 A/μs				
t <sub>rr2</sub>	Reverse recovery time	$I_F = 0.5 \text{ A to } I_R = 1 \text{ A; } I_{rec} = 0.25 \text{ A}$ $I_F = 1 \text{ A; } dI_F/dt = 10 \text{ A/}\mu\text{s}$	-	13	22	ns
$V_{\text{fr}}$	Forward recovery voltage	$I_F = 1 \text{ A}; dI_F/dt = 10 \text{ A/µs}$	-	1	-	V

### Rectifier diodes ultrafast, rugged

### BYV42E, BYV42EB series







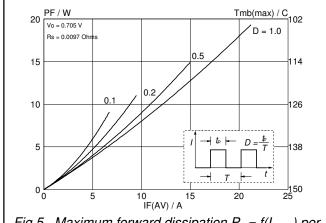
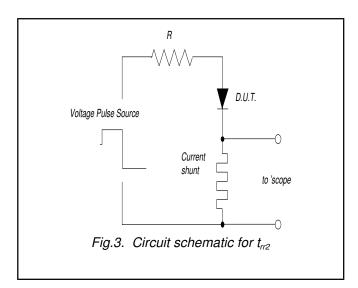


Fig.5. Maximum forward dissipation  $P_F = f(I_{F(AV)})$  per diode; square current waveform where  $I_{F(AV)} = I_{F(RMS)} \ x \ \sqrt{D}$ .



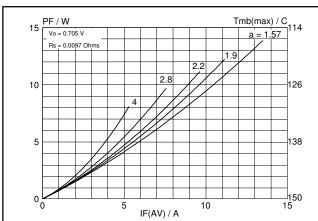
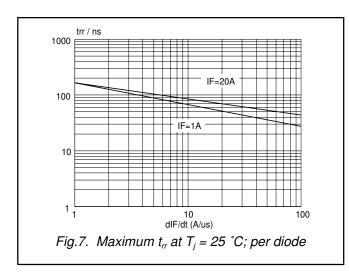
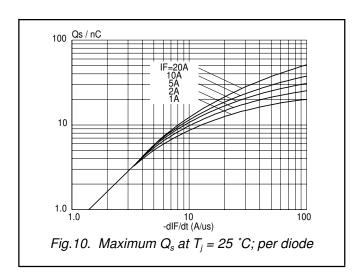


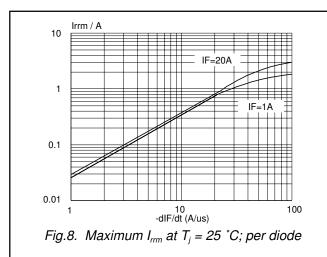
Fig.6. Maximum forward dissipation  $P_F = f(I_{F(AV)})$  per diode; sinusoidal current waveform where a = form factor =  $I_{F(RMS)} / I_{F(AV)}$ .

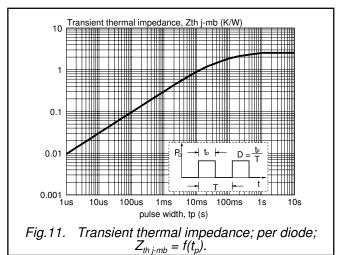
### Rectifier diodes ultrafast, rugged

### BYV42E, BYV42EB series









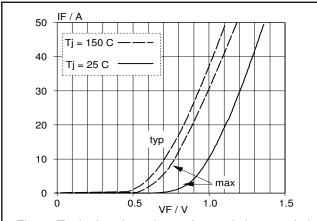
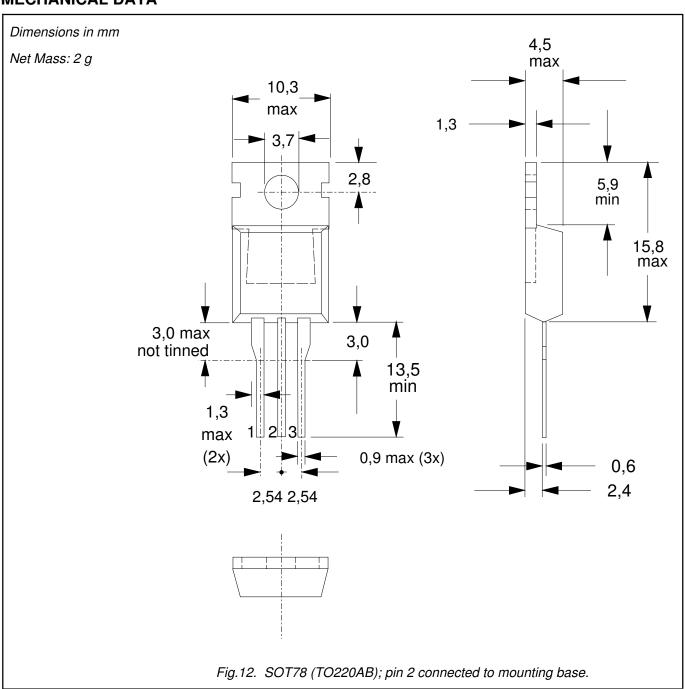


Fig.9. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

Rectifier diodes ultrafast, rugged BYV42E, BYV42EB series

### **MECHANICAL DATA**



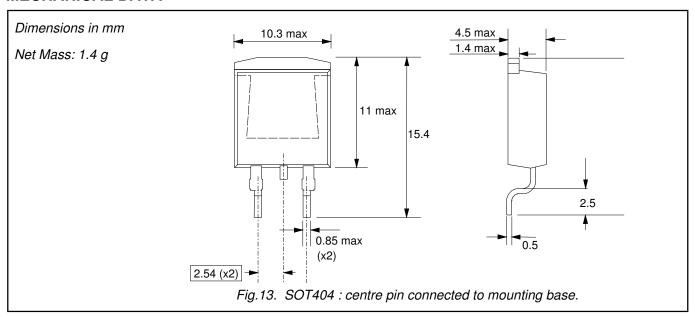
- Notes
  1. Refer to mounting instructions for SOT78 (TO220) envelopes.
  2. Epoxy meets UL94 V0 at 1/8".

NXP Semiconductors Product specification

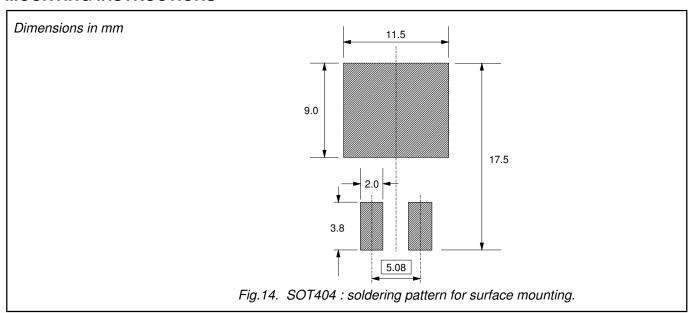
Rectifier diodes ultrafast, rugged

BYV42E, BYV42EB series

### **MECHANICAL DATA**



### **MOUNTING INSTRUCTIONS**



### **Notes**

1. Epoxy meets UL94 V0 at 1/8".

### Legal information

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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